

Bi-Directional Triode Thyristor

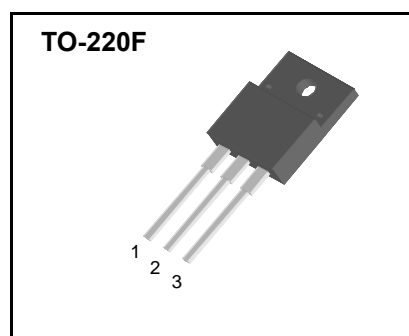
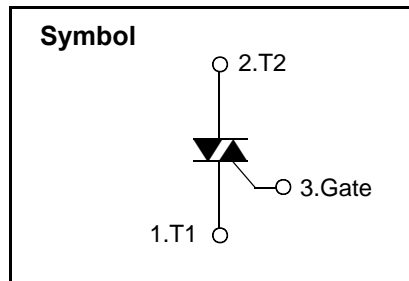
Features

- ◆ Repetitive Peak Off-State Voltage : 600V
- ◆ R.M.S On-State Current ($I_{T(RMS)} = 8\text{ A}$)
- ◆ High Commutation dv/dt
- ◆ Isolation Voltage ($V_{ISO} = 1500\text{V AC}$)

General Description

This device is fully isolated package suitable for AC switching application, phase control application such as fan speed and temperature modulation control, lighting control and static switching relay.

This device is approved to comply with applicable requirements by Underwriters Laboratories Inc.



Absolute Maximum Ratings ($T_J = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Condition	Ratings	Units
V_{DRM}	Repetitive Peak Off-State Voltage		600	V
$I_{T(RMS)}$	R.M.S On-State Current	$T_C = 76^\circ\text{C}$	8.0	A
I_{TSM}	Surge On-State Current	One Cycle, 50Hz/60Hz, Peak, Non-Repetitive	70/77	A
I^2t	I^2t for fusing	$t = 10\text{ms}$	24	A^2s
P_{GM}	Peak Gate Power Dissipation		5.0	W
$P_{G(AV)}$	Average Gate Power Dissipation	Over any 20ms period	0.5	W
I_{GM}	Peak Gate Current		2.0	A
V_{GM}	Peak Gate Voltage		10	V
V_{ISO}	Isolation Breakdown Voltage(R.M.S.)	A.C. 1 minute	1500	V
T_J	Operating Junction Temperature		- 40 ~ 125	$^\circ\text{C}$
T_{STG}	Storage Temperature		- 40 ~ 150	$^\circ\text{C}$
	Mass		2.0	g

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Electrical Characteristics

Symbol	Items		Conditions	Ratings			Unit
				Min.	Typ.	Max.	
I_{DRM}	Repetitive Peak Off-State Current		$V_D = V_{DRM}$, Single Phase, Half Wave $T_J = 125\text{ }^\circ\text{C}$	—	—	1.0	mA
V_{TM}	Peak On-State Voltage		$I_T = 10\text{ A}$, Inst. Measurement	—	—	1.6	V
I_{GT1}^+	I	Gate Trigger Current	$V_D = 6\text{ V}$, $R_L = 10\text{ }\Omega$	—	—	25	mA
I_{GT1}^-	II			—	—	25	
I_{GT3}^-	III			—	—	25	
V_{GT1}^+	I	Gate Trigger Voltage	$V_D = 6\text{ V}$, $R_L = 10\text{ }\Omega$	—	—	1.5	V
V_{GT1}^-	II			—	—	1.5	
V_{GT3}	III			—	—	1.5	
V_{GD}	Non-Trigger Gate Voltage		$T_J = 125\text{ }^\circ\text{C}$, $V_D = 1/2 V_{DRM}$	0.2	—	—	V
$(dv/dt)_c$	Critical Rate of Rise Off-State Voltage at Commutation		$T_J = 125\text{ }^\circ\text{C}$, $[di/dt]_c = -3.0\text{ A/ms}$, $V_D = 2/3 V_{DRM}$	5.0	—	—	V/ μs
I_H	Holding Current			—	10	—	mA
$R_{th(j-c)}$	Thermal Impedance		Junction to case	—	—	3.8	$^\circ\text{C/W}$



Fig 1. Gate Characteristics

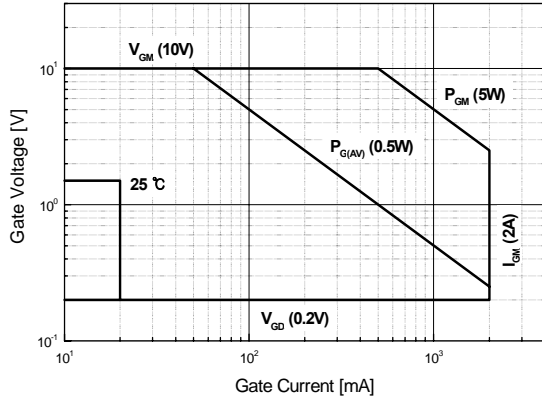


Fig 2. On-State Voltage

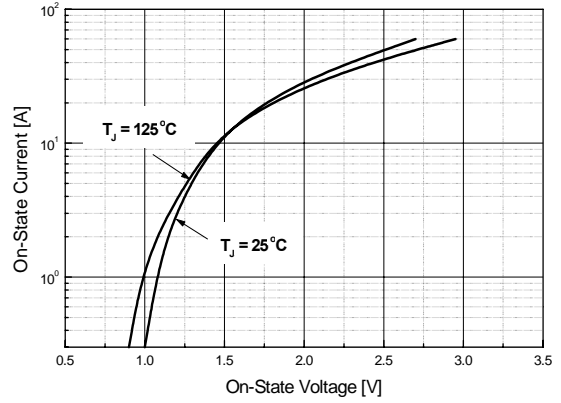


Fig 3. On State Current vs. Maximum Power Dissipation

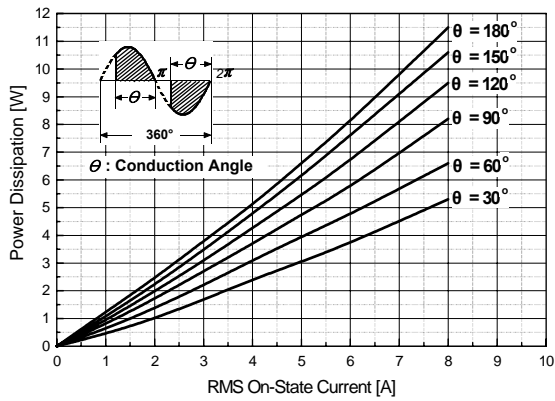


Fig 4. On State Current vs. Allowable Case Temperature

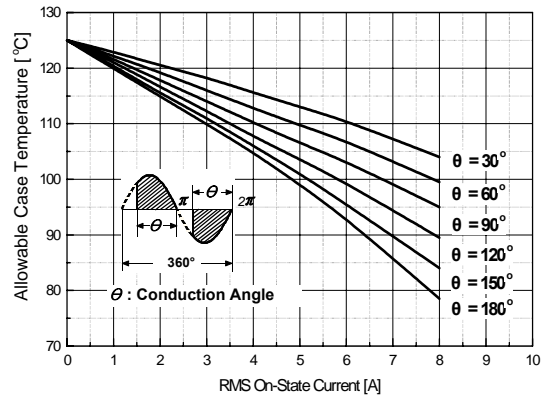


Fig 5. Surge On-State Current Rating (Non-Repetitive)

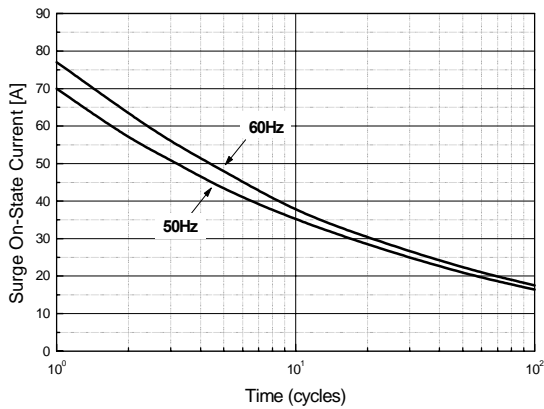
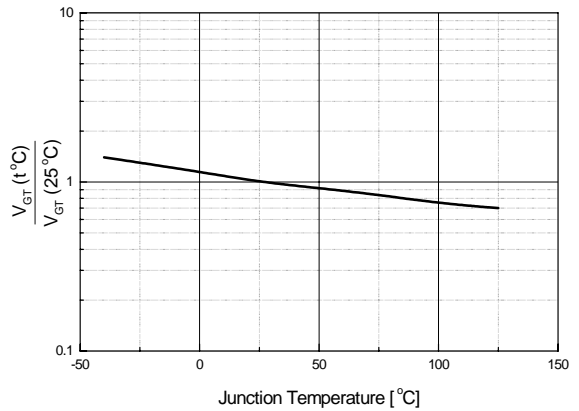


Fig 6. Gate Trigger Voltage vs. Junction Temperature



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Fig 7. Gate Trigger Current vs. Junction Temperature

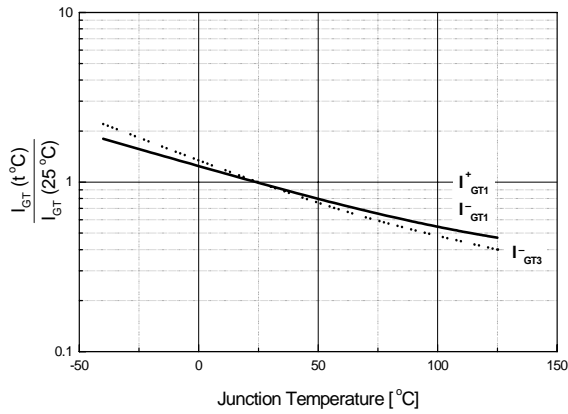


Fig 8. Transient Thermal Impedance

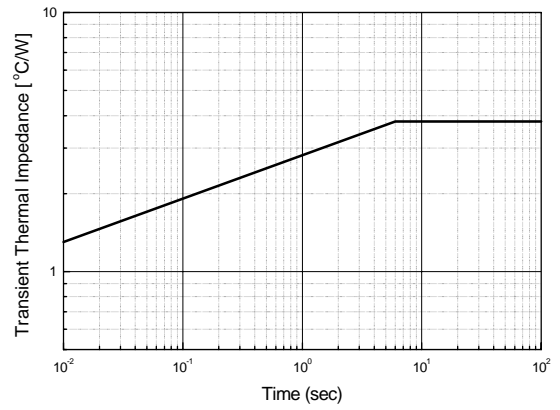
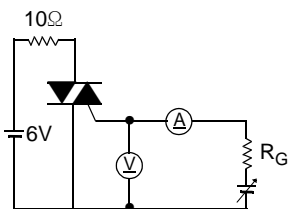
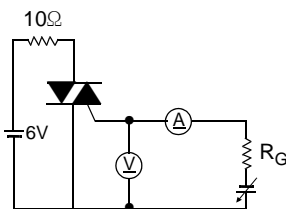


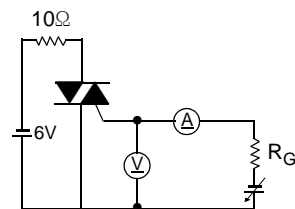
Fig 9. Gate Trigger Characteristics Test Circuit



Test Procedure I



Test Procedure II



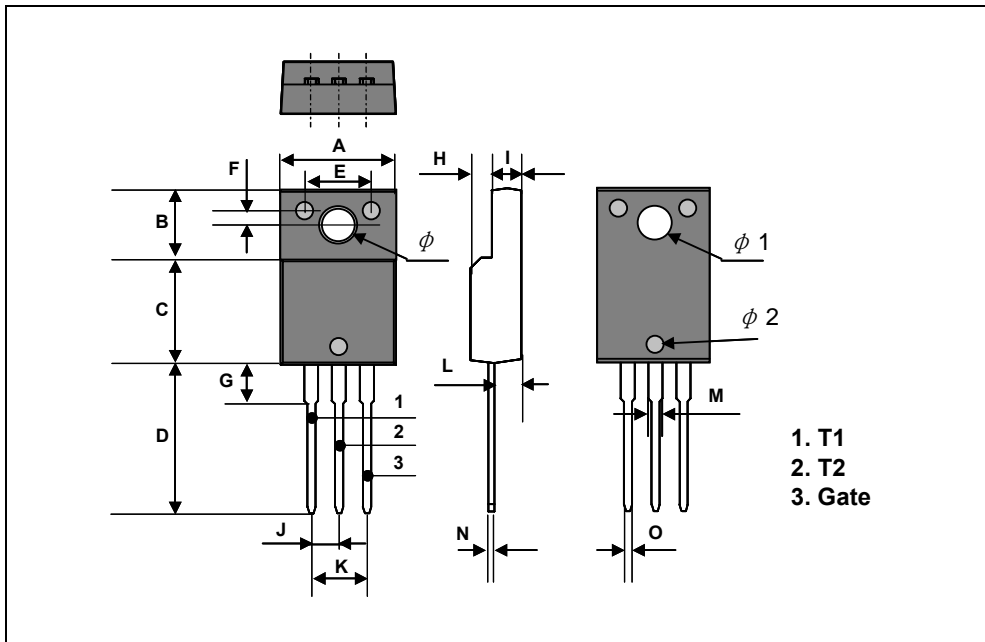
Test Procedure III



BT137F-600

TO-220F Package Dimension

Dim.	mm			Inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	10.4		10.6	0.409		0.417
B	6.18		6.44	0.243		0.254
C	9.55		9.81	0.376		0.386
D	13.47		13.73	0.530		0.540
E	6.05		6.15	0.238		0.242
F	1.26		1.36	0.050		0.054
G	3.17		3.43	0.125		0.135
H	1.87		2.13	0.074		0.084
I	2.57		2.83	0.101		0.111
J		2.54			0.100	
K		5.08			0.200	
L	2.51		2.62	0.099		0.103
M	1.25		1.55	0.049		0.061
N	0.45		0.63	0.018		0.025
O	0.6		1.0	0.024		0.039
ϕ		3.7			0.146	
$\phi 1$		3.2			0.126	
$\phi 2$		1.5			0.059	



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TO-220F Package Dimension, Forming

Dim.	mm			Inch		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	10.4		10.6	0.409		0.417
B	6.18		6.44	0.243		0.254
C	9.55		9.81	0.376		0.386
D	8.4		8.66	0.331		0.341
E	6.05		6.15	0.238		0.242
F	1.26		1.36	0.050		0.054
G	3.17		3.43	0.125		0.135
H	1.87		2.13	0.074		0.084
I	2.57		2.83	0.101		0.111
J		2.54			0.100	
K		5.08			0.200	
L	2.51		2.62	0.099		0.103
M	1.25		1.55	0.049		0.061
N	0.45		0.63	0.018		0.025
O	0.6		1.0	0.024		0.039
P		5.0			0.197	
ϕ		3.7			0.146	
$\phi 1$		3.2			0.126	
$\phi 2$		1.5			0.059	

